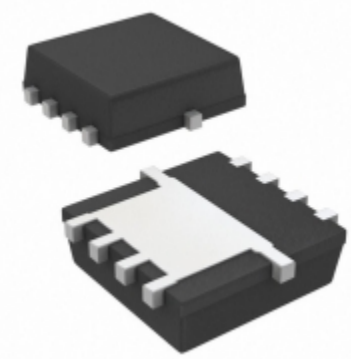


SI7804DN-T1-E3	
Teilenummer	SI7804DN-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 6.5A 1212-8
Verfügbare Menge	790 pcs in stock
Datenblätter	
SI7804DN-T1-E3 Price	Preis und Lieferzeit online anfordern or Email us: Info@ariat-tech.com


[EIN ANGEBOT BEKOMMEN](#)

Technische Information von SI7804DN-T1-E3			
Hersteller-Teilenummer	SI7804DN-T1-E3	Kategorie	Diskrete Halbleiterprodukte
Hersteller	Electro-Films (EFI) / Vishay	Beschreibung	MOSFET N-CH 30V 6.5A 1212-8
Paket / Fall	Tape & Reel (TR)	Verfügbare Menge	790
Hersteller Standard Vorlaufzeit	33 Weeks	detaillierte Beschreibung	N-Channel 30V 6.5A (Ta) 1.5W (Ta) Surface Mount PowerPAK® 1212-8
Serie	TrenchFET®	Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)	Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® 1212-8	Supplier Device-Gehäuse	PowerPAK® 1212-8
Verlustleistung (max)	1.5W (Ta)	Typ FET	N-Channel
FET-Merkmal	-	Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	6.5A (Ta)	Rds On (Max) @ Id, Vgs	18.5 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	1.8V @ 250µA	Gate Charge (Qg) (Max) @ Vgs	13nC @ 5V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V	Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)	Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)	Andere Namen	SI7804DN-T1-E3TR

SI7804DN-T1-E3 790 pcs Neu und original auf Lager, SI7804DN-T1-E3-Bestand finden, Datenblatt, PDF, Inventar bei Ariat-Tech.com online, SI7804DN-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen bestellen. Anfrage SI7804DN-T1-E3: Info@Ariat-Tech.com

Zugehörige Teile für SI7804DN-T1-E3				
Bild	Teilenummer	Beschreibung	Hersteller	Menge
	SI7800ADN	SI7800ADN SI	SI	4 pcs
	SI7806ADN-T1-E3	MOSFET N-CH 30V 9A 1212-8	Vishay / Siliconix	25300 pcs
	SI7806ADN-T1-GE3	MOSFET N-CH 30V 9A 1212-8	Vishay / Siliconix	25500 pcs
	SI7804DN-T1-GE3	MOSFET N-CH 30V 6.5A 1212-8	Vishay / Siliconix	500 pcs
	SI7804DN	SI7804DN SI	SI	831 pcs
	SI7804DN-T1-GE3	MOSFET N-CH 30V 6.5A 1212-8	Electro-Films (EFI) / Vishay	500 pcs
	SI7804DN-T1-E3	MOSFET N-CH 30V 6.5A 1212-8	Vishay / Siliconix	790 pcs
	SI7802DN	SI7802DN SI	SI	33 pcs
	SI7806ADN-T1-E3	MOSFET N-CH 30V 9A 1212-8	Electro-Films (EFI) / Vishay	25300 pcs
	SI7806ADN	SI7806ADN SI	SI	36135 pcs
	SI7798DP-T1-GE3	SI7798DP-T1-GE3 VISHAY	Vishay	2231 pcs
	SI7794DP-T1-GE3	MOSFET N-CH 30V P-PACK SO-8	Electro-Films (EFI) / Vishay	2798 pcs
	SI7802DN-T1-E3	MOSFET N-CH 250V 1.24A 1212-8	Electro-Films (EFI) / Vishay	74 pcs
	SI7802DN-T1-E3	MOSFET N-CH 250V 1.24A 1212-8	Vishay / Siliconix	74 pcs
	SI7806AEDN	SI7806AEDN VISHAY	Vishay	99 pcs
	SI7802DN-T1-GE3	MOSFET N-CH 250V 1.24A 1212-8	Vishay / Siliconix	500 pcs
	SI7806ADN-T1-GE3	MOSFET N-CH 30V 9A 1212-8	Electro-Films (EFI) / Vishay	25500 pcs
	SI7806AEDN-T1-E3	SI7806AEDN-T1-E3 VISHAY	Vishay	4500 pcs
	SI7806ADN-T1-E3-PBF	SI7806ADN-T1-E3-PBF VISHAY	Vishay	2160 pcs
	SI7802DN-T1-GE3	MOSFET N-CH 250V 1.24A 1212-8	Electro-Films (EFI) / Vishay	500 pcs

IC Chips & IGBT Modul - Hot Stock Teilenummer

SI7738DP-T1-GE3	SI7738DP-T1-GE3	SI7742DP-T1-E3	SI7742DP-T1-GE3	SI7742DP-T1-GE3
SI7748DP-T1-GE3	SI7748DP-T1-GE3	SI7758DP	SI7758DP-T1-GE3	SI7758DP-T1-GE3
SI7772DP-T1-GE3	SI7772DP-T1-GE3	SI7774DP-T1-GE3	SI7774DP-T1-GE3	SI7784DP-T1-GE3
SI7784DP-T1-GE3	SI7788DP-T1-GE3	SI7788DP-T1-GE3	SI7790DP-T1-E3	SI7790DP-T1-GE3
SI7790DP-T1-GE3	SI7792DP-T1-GE3	SI7794DP-T1-GE3	SI7798DP-T1-GE3	SI7804DN
SI7804DN-T1-E3	SI7806ADN	SI7806ADN-T1-E3	SI7806ADN-T1-E3	SI7806ADN-T1-E3-PBF
SI7806ADN-T1-GE3	SI7806ADN-T1-GE3	SI7806AEDN-T1-E3	SI7806BDN	SI7806BDN-T1-GE3
SI7806DN-T1-E3	SI7806DN-T1-GE3	SI7810DN	SI7810DN-T1	SI7810DN-T1-E
SI7810DN-T1-E3	SI7810DN-T1-E3	SI7812DN-T1-E3	SI7812DN-T1-E3	SI7812DN-T1-GE3
SI7812DN-T1-GE3	SI7818DN-T1-E3	SI7818DN-T1-E3	SI7820DN-T1-E3	SI7820DN-T1-E3

Händler für Elektronikkomponenten - IC-Chips & IGBT-Modullieferant.

Angebotsanfrage E-Mail: Info@ariat-tech.com Webseite: <https://www.ariat-tech.com>

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